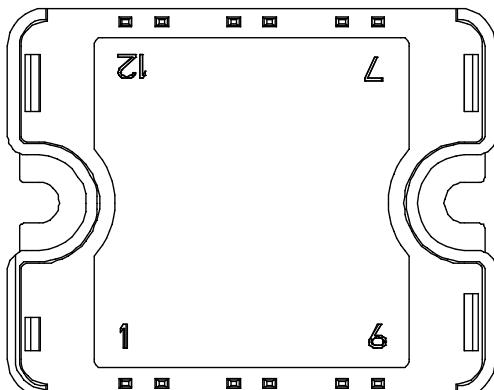
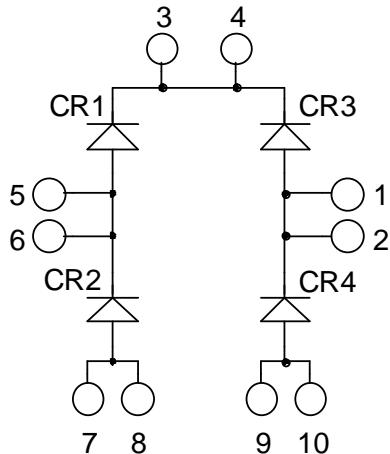


***SiC Diode Full Bridge
Power Module***
 $V_{RRM} = 600V$
 $I_F = 20A @ T_c = 80^\circ C$


All multiple inputs and outputs must be shorted together
 3/4 ; 5/6 ; 7/8 ; 1/2 ; 9/10

Absolute maximum ratings

Symbol	Parameter	Max ratings		Unit
V_R	Maximum DC reverse Voltage	600		V
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			
$I_{F(AV)}$	Maximum Average Forward Current	Duty cycle = 50%	$T_c = 80^\circ C$	20
I_{FSM}	Non-Repetitive Forward Surge Current	10 μs	$T_c = 25^\circ C$	250

 **CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

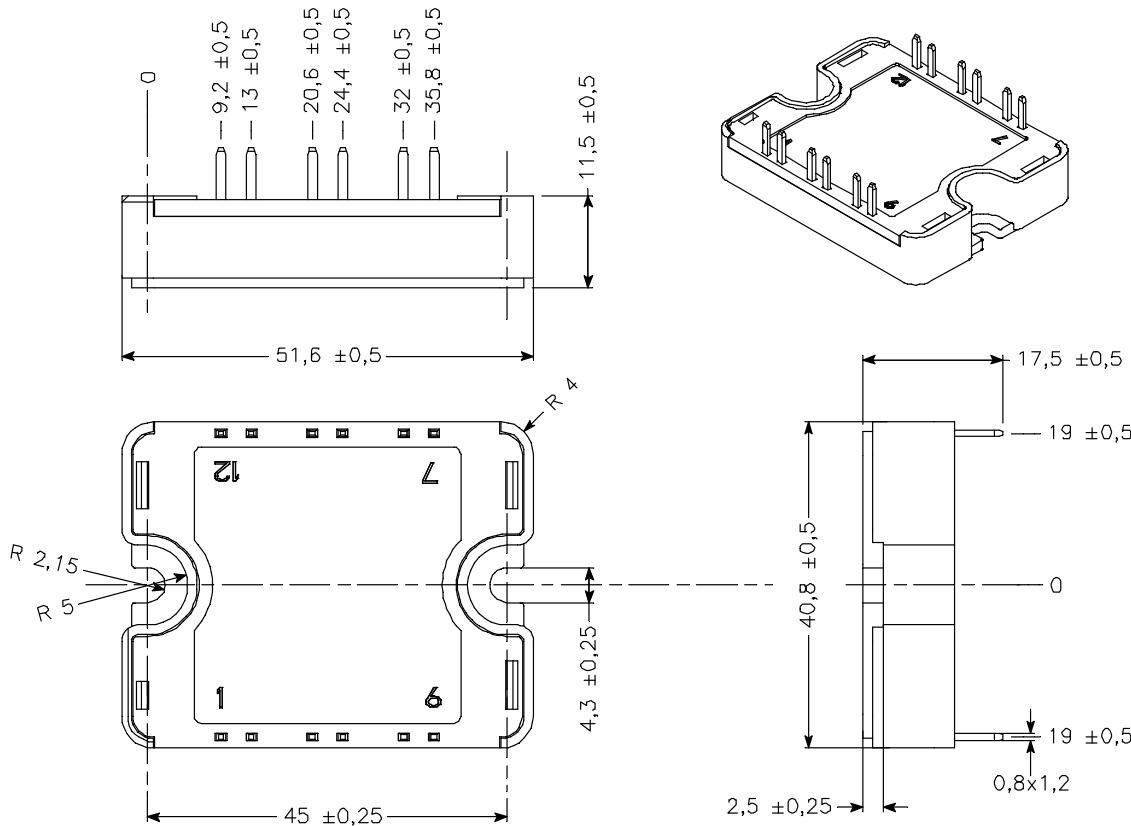
All ratings @ $T_j = 25^\circ\text{C}$ unless otherwise specified

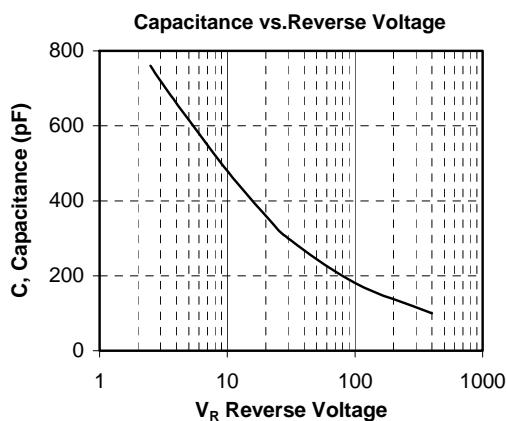
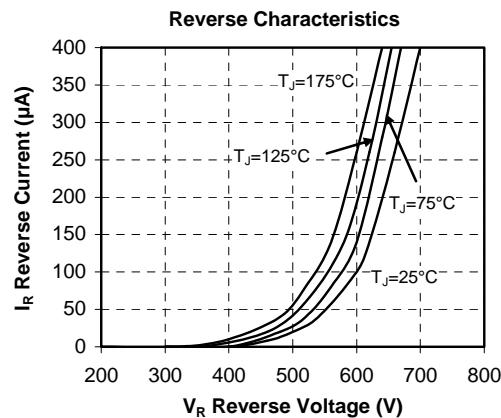
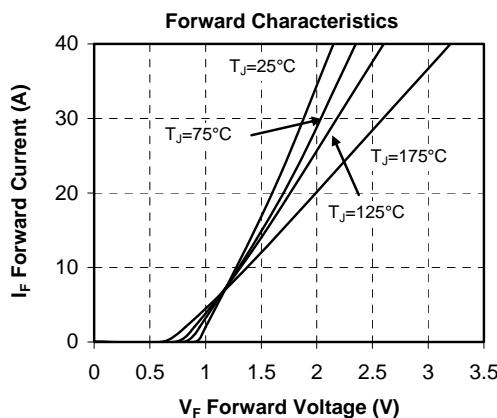
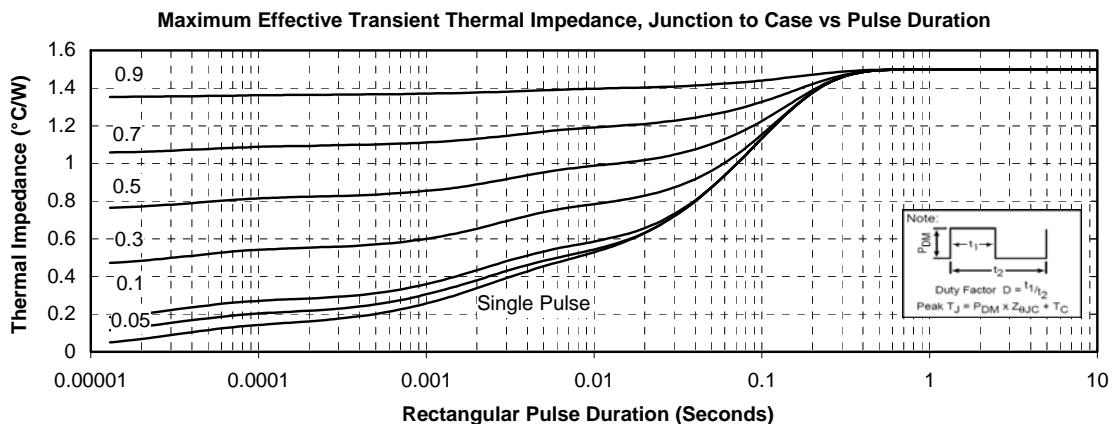
Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
V_F	Diode Forward Voltage	$I_F = 20\text{A}$	$T_j = 25^\circ\text{C}$		1.6	1.8
			$T_j = 175^\circ\text{C}$		2	2.4
I_{RM}	Maximum Reverse Leakage Current	$V_R = 600\text{V}$	$T_j = 25^\circ\text{C}$		100	400
			$T_j = 175^\circ\text{C}$		200	2000
Q_C	Total Capacitive Charge	$I_F = 20\text{A}, V_R = 300\text{V}$ $\text{di/dt} = 800\text{A}/\mu\text{s}$		28		nC
C	Total Capacitance	$f = 1\text{MHz}, V_R = 200\text{V}$		130		pF
		$f = 1\text{MHz}, V_R = 400\text{V}$		100		

Thermal and package characteristics

Symbol	Characteristic	Min	Typ	Max	Unit	
R_{thJC}	Junction to Case Thermal Resistance			1.5	°C/W	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, $I_{isol} < 1\text{mA}$, 50/60Hz	2500			V	
T_j	Operating junction temperature range	-40		175	°C	
T_{STG}	Storage Temperature Range	-40		125		
T_c	Operating Case Temperature	-40		100		
Torque	Mounting torque	To heatsink	M4	2.5	4.7	N.m
Wt	Package Weight			80	g	

SP1 Package outline (dimensions in mm)

 See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

Typical Performance Curve


Microsemi reserves the right to change, without notice, the specifications and information contained herein

Microsemi's products are covered by one or more of U.S patents 4,895,810 5,045,903 5,089,434 5,182,234 5,019,522 5,262,336 6,503,786 5,256,583 4,748,103 5,283,202 5,231,474 5,434,095 5,528,058 6,939,743 7,352,045 5,283,201 5,801,417 5,648,283 7,196,634 6,664,594 7,157,886 6,939,743 7,342,262 and foreign patents. U.S and Foreign patents pending. All Rights Reserved.